SILICON RECTIFIERS

Voltage Range - 50 to 1000 Volts **Current – 1.0 Amperes**

Features

- High reliability
- Low leakage
- Low forward voltage drop
- · High current capability

Mechanical Data

- Case: Molded plastic black body
- Lead: MIL-STD 202E method 208C guaranteed.
- Mounting Position: Any

Dimensions in mm

20 0 min

Absolute Maximum Ratings and Characteristics

Ratings at 25°Cambient temperature unless otherwise specified.. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

-7	Symbols	1A1	1A2	1A3	1A4	1A5	1A6	1A7	Units
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at $T_A = 25$ $^{\circ}$ C	Io		•		1.0	7	TO S	70	Α
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	25 W W W. 0 Z S							А
Maximum instantaneous forward voltage at 1A DC	V _F	1.1						V	
Maximum DC reverse current at rated DC blocking voltage $@T_A = 25^{\circ}C$ $@T_A = 100^{\circ}C$	lo.	5.0 I _R 50							uA
Maximum full load reverse current full cycle average 0.375" (9.5mm) lead length at T _L =75°C		100						300	uA
Typical junction capacitance (note)	CJ	15							pF
Typical thermal resistance	$R_{\theta JA}$	60							°C/W
Operating and storage temperature range	T _J ,T _S	-65 to +150							°С

Note: Measured at 1MHz and applied reverse voltage of 4V. WWW.DZSC



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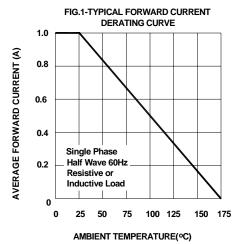
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Dated: 08/09/2003



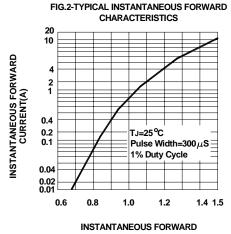
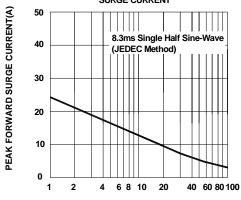
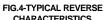


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT





VOLTAGE(V)

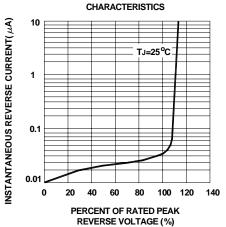
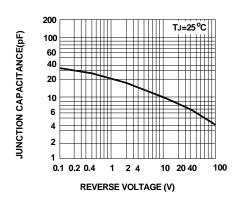


FIG.5-TYPICAL JUNCTION CAPACITANCE

NUMBER OF CYCLES AT 60 Hz





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